ILA3354

IC for Electronic Ballasts

Short Description

The bipolar monolithic integrated circuit triggers, monitors and turns-off RF-oscillation of an electronic ballast for fluorescent lamps dependent on several controland monitoring functions.

Features

Minimum wiring complexity Overtemperature protection without external components

Malfunction detection

Timer output

Automatical reignition after lamp change

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Pin 1	TM	temperature mode selection
Pin 2	CT	clock generator
Pin 3	TR	trigger output, turn-off attenuation, oscillation detector
Pin 4	GND	connection to ground
Pin 5	EI	error indication input
Pin 6	LW	input of lamp change
Pin 7	S	switching output of the timer
Pin 8	V _{CC}	supply voltage



Characteristics of the IC

• The ILA3354 is a control- and monitoring-IC to drive an electronic ballast for fluorescent lamps.

• The IC actuates the oscillation of a self-oscillating circuit for generation of RF-shaped lamp current by means of trigger pulses. After successful excitation the oscillation is monitored and further trigger pulses are blocked.

• The IC has a timer with low-active output which is activated for one second after supply voltage was applied.

The switching output is effective for pre-heating and ignition systems.

• The IC consists an error indication input. In case of error indication the IC stops oscillation. Enquiry cycles realize interference reduction.

• After lamp change the IC starts oscillation again.

• The IC protects from overtemperature cutting oscillation. It is programmable when the oscillator circuit shall be triggered again.



Functional Description

At the moment of current feeding at terminal V_{CC} , the IC generates the supply voltage via backup capacitor externally connected. As soon as an internal switching threshold of 7 V is reached, trigger pulses are delivered at the output TR with a repetition instalment of 960 μ s. After successful triggering of the oscillator circuit, an oscillation detector guarantees blocking of further trigger pulses. It identifies a stable oscillating process, after a minimum of oscillations is detected per timing.

As soon as a switching threshold of 8 V is reached, all logic units are reset and the timer output S is activated as well. The IC starts a counter, which interrups the control after one second.

Furthermore, the IC monitors the temperature and the oscillation circuit from a supply voltage of 8 V. The comparator input EI is useful for error detection. Voltage > 3.75 V, applied at EI, are evaluated as error signals. The error signal is enqired and registered within a cycle repeating every 960 µs. After registration of the error signal, a counter starts to generate a delay of one second. After this delay time, the voltage at EI is evaluated again. The error storage is set only after a second error, appearing within a directly following evaluation cycle. This error storage is resettable by a short-time power supply disconnection, or with input LW connected via a change of lamp.

The error storing causes the cutting further triggers and the control of the turn-off transistor as well, which turns the output TR to ground. Therefore, the turn-off transistor prevents the control of the oscillator circuit, attenuating it extremly quickly.

Thereby, the current consumption increases by the control of the turn-off transistor. This current amounts more than 5 mA, that the supply voltage across the backup capacitor at pin V_{CC} breaks down (because nominal current

feed is less 5 mA). With a switching threshold of 6 V, the control current of the turn-off transistor is switched off, that enables the supply voltage to rise up to the limiting voltage. Because the trigger pulse gate, blocked by the error memory, the oscillation can't start again.

With error storing and attenuation of the oscillation by overtemperature it can be defined via selection of the temperature mode, whether the oscillation is automatically triggered after cooling-down of the assembly, or only after mains disconnection.

	Pin	Symbol	min	max	unit
current consumption	V _{CC}	I_{CCeff}		20	mA
peak current for t< 100 µs	V _{CC}	I _{CCM}		100	mA
input voltage error indicator	EI	V_{Err}	-0.3	V _{CC}	V
input voltage lamp exchange input	LW	V_{LW}	-0.3	15	V
voltage difference between V_{LW} and V_{CC} for divider factor 16 via LW	LW	V _{LW} V _{CC}		6	V
input current at pin TM	ТМ	ITM		1	mA
negative current load for t<1µs with max. repeat frequency = 200kHz	TR	I _{TR(neg.)}	-500		mA
switching output current	S	IS		1	mA
junction temperature		тj		150	°C
storage temperature		T _{stg}	-50	150	°C
ambient temperature		T_{amb}	-20	120	°C
ESD protection		V _{ESD}		2	kV

Absolute Maximum Ratings



Characteristics

with Tamb = 25 °C, V_{CC} = 10 V, unless specified otherwise

	Pin	Symbol	min	typ	max	unit
range for internal voltage	V _{CC}	V_{lim}	10.8	11.4	12	V
limitation						
quiescent current	V _{CC}	I _{CC(on)}		1.25	1.5	mA
consumption						
trigger repeat rate with	TR	t _{TRW}	900	1000	1100	μs
$C_{Clock} = 82 pF$						
output pulse current	TR	I _{TRM}	400	650	850	mA
on 10 Ω						
output pulse width with	TR	t _{TR}	0.6	0.9	1.5	μs
90% amplitude						
saturation voltage of	TR	V _{TRsat}		380	500	mV
turn-off transistor						
with I=450 mA						
saturation voltage of	S	V_{Ssat}		0.2	0.45	V
switching output						
response level of error	EI	K _{OL}	3.60	3.75	3.90	V
voltage						
switching point of		Ts	95	105	115	°C
overtemperature turn-off						
switching range to indicate	LW	V_{LE}			3.25	V
a lamp as removed						
switching range to indicate	LW	V_{LV}	4.25		^v CC	V
a lamp as applied						

Parameter	Condition	Value	Unit
Threshold for connecting the trigger pulses during build-up phase	$C_{Clock} = 82 pF$	7	V
Threshold for release of the internal reset	$C_{Clock} = 82 pF$	8	V
Threshold for switching-off the control of the turn-off transistor with set error memory	$f C_{Clock} = 82 pF$	6	V
Delay of response with error detection	$C_{Clock} = 82 pF$	1	S
Duration for activation switching output	$C_{Clock} = 82 pF$	1	S
Duration needed for rating at least 4 pulse-shaped distortions or a static error signal with twice interrogation within delay time 1 sec	$C_{Clock} = 82 pF$	840	μs
Control current of the turn-off transistor	$C_{Clock} = 82 pF$	10	mA
Temperature hysteresis for re-ignition after overtemperature switch-off (pin TM is connected to ground)	$C_{Clock} = 82 pF$	10	°C







Principle Circuit Diagram



Application Circuit Diagram





Package Dimension



N SUFFIX PLASTIC DIP (MS - 001BA)

NOTES:

 Dimensions "A", "B" do not include mold flash or protrusions. Maximum mold flash or protrusions 0.25 mm (0.010) per side.

8 1

	Dimension, mm		
Symbol	MIN	MAX	
Α	8.51	10.16	
В	6.1	7.11	
С		5.33	
D	0.36	0.56	
F	1.14	1.78	
G	2.54		
Н	7.62		
J	0°	10°	
К	2.92	3.81	
L	7.62	8.26	
Μ	0.2	0.36	
Ν	0.38		

